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Temperature dependence of Peierls–Hubbard phase transition in $[\text{Pd}(\text{cptn})_2\text{Br}]\text{Br}_2$ studied by scanning tunneling microscopy

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The temperature dependence of the Peierls–Hubbard phase transition in $[\text{Pd}(\text{cptn})_2\text{Br}]\text{Br}_2$ (cptn: 1*R*,2*R*-diaminocyclopentane) was directly observed using a low-temperature scanning tunneling microscope. A short ligand without alkyl chains was used to form a rigid crystal lattice to reduce the effect of structural changes in the crystal with temperature. The hysteresis in the temperature dependence of the ratio between the areas of the charge density wave (CDW) state produced by the $\text{Pd}^{\text{II}}\text{–Pd}^{\text{IV}}$ mixed-valence state and the Mott–Hubbard (MH) state with a Pd^{III} -averaged valence state which is a characteristic of the first-order phase transition, was directly observed at the atomic scale. Pinning of the CDW phase by defects was observed below the critical temperature, suggesting the growth of the CDW phase with defects as nuclei.

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1. Introduction

Low-dimensional materials have been extensively studied because of their novel physical properties, for example, in strongly correlated electron systems and π -conjugate systems. Among these materials, quasi-one-dimensional (quasi-1D) halogen-bridged complexes (MX chains), in which isolated 1D electron systems are composed of d_{z^2} -orbitals of metal ions (M) and p_z -orbitals of bridging halide ions (X) in M–X–M–X– linear chain structures, have been attracting considerable attention owing to their strong Coulomb interaction observed in phenomena such as resonance Raman spectra^{1–4} and spin-Peierls transitions.⁵ Although more than 300 species of quasi-1D organic complexes have been synthesized, mainly using Ni or Pt metal ions, that exhibit mixed valence states, it has been theoretically predicted that a compound complex with Pd metal will undergo a charge transfer phase transition owing to the strong competition between the energies of the electron–phonon interaction (S) and on-site Coulomb repulsion (U), i.e., the transfer integral (T).^{6–10} This is a characteristic of Pd compounds called the Peierls–Hubbard phase transition and has recently been experimentally confirmed using $[\text{Pd}(\text{en})_2\text{Br}](\text{C}_5\text{-Y})_2\cdot\text{H}_2\text{O}$ (en: ethylenediamine; $\text{C}_5\text{-Y}$: dipentylsulfosuccinate), which exhibits the phase transition between the charge density wave (CDW) and Mott–Hubbard (MH) states at 205 K.¹¹

$\text{Pd}\text{-MX}$ chains form an $\text{M}^{\text{II}}\text{–M}^{\text{IV}}$ mixed-valence state at room temperature (RT), where the bridging halide ions are displaced from the midpoints between two neighboring metal ions as shown in Fig. 1(a). M^{II} and M^{IV} denote divalent and quadrivalent metals, respectively. The structure shown in Fig. 1(a) is the charge density wave produced by the strained 1D structure (Peierls deformation) caused by a large S , which forms a twofold periodicity. On the other hand, at a low temperature, an M^{III} -averaged valence state, the so-called MH state, is formed owing to the large U , in which the bridging halogens are located at the midpoints between two neighboring metal ions without modulation, as shown in Fig. 1(b). The d_{z^2} bands of Pd^{II} and Pd^{IV} in the CDW state form a conduction band and a valence band, respectively,¹² while the d_{z^2} band of Pd^{III} in the MH state splits into the

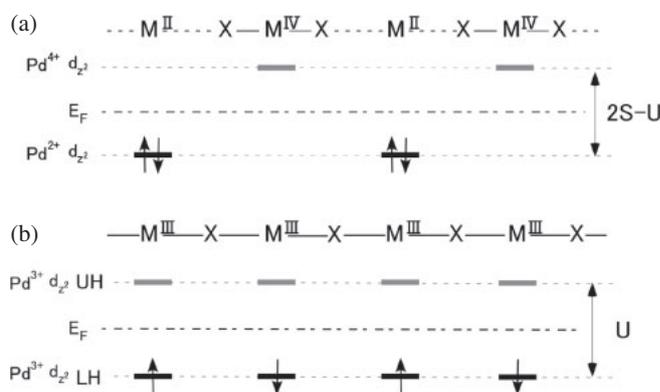


Fig. 1. Schematic structures of (a) CDW and (b) MH states. Arrows indicate spins. The d_{z^2} bands of Pd^{II} and Pd^{IV} in the CDW state form a conduction band and a valence band, respectively, while the d_{z^2} band of Pd^{III} in the MH state splits into the unoccupied UH and the occupied LH, owing to the strong interaction between electrons. E_F indicates Fermi energy.

unoccupied upper Hubbard band (UH) and occupied lower Hubbard band (LH), owing to the strong interaction between electrons.

The phase transition associated with the structural change shown in Fig. 1 has been experimentally observed by various methods such as infrared (IR) spectroscopy, X-ray diffraction analysis, and scanning tunneling microscopy (STM).¹¹ Although these studies revealed details of the phase transition, they were carried out for Pd complexes including ligands with long alkyl groups. For a sample with a long alkyl chain, a larger change in the Pd–Pd distance in the b -axis direction with temperature is considered to affect the study of the characteristics at around the critical temperature.^{6–10,13,14}

Here, we present the first results of the STM observation of the temperature dependence of the structural change of CDW–MH phases in $[\text{Pd}(\text{cptn})_2\text{Br}]\text{Br}_2$ (cptn: 1*R*,2*R*-diaminocyclopentane). A sample with a short ligand without alkyl chains was used in our experiment to form a rigid crystal lattice to attenuate the effect of structural changes in the crystal with temperature.

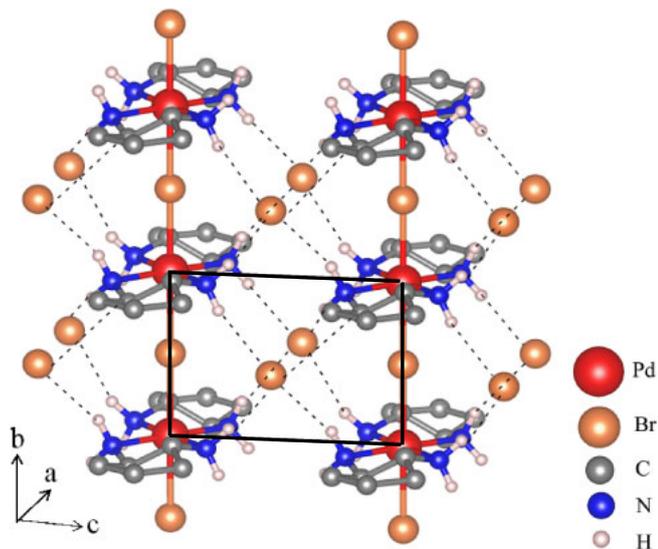


Fig. 2. (Color online) Schematic of the crystal structure of $[\text{Pd}(\text{cptn})_2\text{Br}]\text{Br}_2$ (cptn: 1*R*,2*R*-diaminocyclopentane).

2. Experimental procedure

Figure 2 shows the crystal structure of $[\text{Pd}(\text{cptn})_2\text{Br}]\text{Br}_2$, an octahedral structure consisting of four N atoms (two ligands) and two Br atoms placed around a Pd atom, in which the d_{z^2} and $d_{x^2-y^2}$ orbitals respectively extend vertically along the b -axis and in the four side directions. The d_{z^2} orbital of Pd and the p_z orbital of Br strongly overlap and are alternately ordered to form a quasi-one-dimensional (quasi-1D) halogen-bridged complex.

The $[\text{Pd}(\text{cptn})_2\text{Br}]\text{Br}_2$ crystal has a unit cell of $a = 2.39$ nm, $b = 0.707$ nm, and $c = 0.529$ nm, which develops a two-fold periodicity along the b -axis in the CDW phase, and can be directly observed by STM.^{14–22} Single-crystal $[\text{Pd}(\text{cptn})_2\text{Br}]\text{Br}_2$ samples were grown by the electrochemical oxidation method,²³ which were cut and fixed on a sample stage with carbon paste. Experiments were carried out using an Omicron low-temperature scanning tunneling microscope with a base pressure of 10^{-9} Pa. The performance of a piezo scanner at low temperatures was calibrated using a Si(001) surface structure. Measurement below 100 K was not possible in our experiment because of the difficulty in making the microscope tip approach the sample owing to the large decrease in the conductivity in the MH state. In addition, when a negative bias voltage was applied to the sample, the sample surface was damaged, which may have been caused by the reduced number of carriers in the surface region of the sample. Although the details are not yet clear, all measurements reported in this paper were carried out with a positive bias voltage applied to the sample.

The sample temperature, which was measured by a thermocouple attached to the sample stage, was controlled using a resistive heater attached near the sample stage, which was cooled using liquid N_2 . Thermal drift was suppressed by keeping the sample at each temperature for a sufficient time before measurements, which varied from 1–2 h to overnight depending on the conditions.

3. Results and discussion

Figure 3 shows typical STM images of the $[\text{Pd}(\text{cptn})_2\text{Br}]\text{Br}_2$

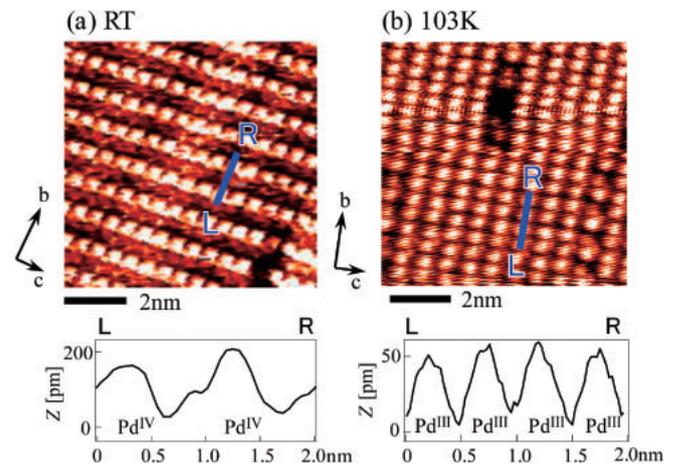


Fig. 3. (Color) STM images of $[\text{Pd}(\text{cptn})_2\text{Br}]\text{Br}_2$ surfaces obtained at (a) RT ($V_s = 1.5$ V, $I_t = 0.08$ nA) and (b) 103 K ($V_s = 4.0$ V, $I_t = 0.1$ nA).

b - c plane obtained at (a) RT and (b) 103 K, where the Pd atoms shown in Fig. 2 are imaged as bright spots similarly to that in a previous paper.^{11,14} Cross sections along the blue lines in the STM images are shown together, where L and R show the positional relationship. As shown in Fig. 3, the periodicities along the b - and c -axes are (a) (0.98 nm, 0.68 nm) and (b) (0.49 nm, 0.69 nm), respectively. Since the STM image showing the twofold periodicity is similar to that obtained at RT in a previous study and the original periodicity appeared at lower temperatures, as expected, we attributed those structures to the $\text{Pd}^{\text{II}}\text{-Br-Pd}^{\text{IV}}$ CDW state at RT and to the $\text{Pd}^{\text{III}}\text{-Br-Pd}^{\text{III}}$ MH state at 103 K, respectively. The bright protrusions were attributed to the Pd d_{z^2} orbital, similarly to those in the previous image obtained at RT.

Next, we directly observed the temperature dependence of the phase transition. Figure 4 shows the change in the STM images of the $[\text{Pd}(\text{cptn})_2\text{Br}]\text{Br}_2$ b - c plane with decreasing [(a) to (c)] and increasing [(d) and (e)] temperature. The area ratios between the CDW and MH phases shown above the STM images were obtained from the average of the STM images measured over 25×25 nm² areas at different locations at each temperature. First, the temperature was stabilized at 155 K by adjusting the current of the heater, and the required images were taken. Then the temperature was decreased to 113 and 103 K and then increased to 115 and 158 K in a stepwise manner by changing the current of the heater, and images were taken at each temperature. Thermal drift was suppressed by keeping the sample at each temperature for a sufficient time before measurements, as described above, which also ensured accurate temperature control. Cross sections along the lines in the STM images are shown together.

As shown in Figs. 4(a) and 4(e), almost the entire surface was occupied by the 2×1 CDW phase at 155 K, while, as shown in Fig. 4(c), almost the entire surface was covered by the MH state at 103 K; the CDW/MH area ratio was 1 : 9, confirming that the CDW and MH phases appear at high and low temperatures, respectively. Here, the CDW phase comprising $\sim 1/10$ of the surface area at 103 and 115 K was observed around the defects, as shown in Figs. 4(c) and 4(d), respectively. Figure 4(f) shows a cross section along the 1D chain of Pd atoms surrounded by the dashed rectangle in the

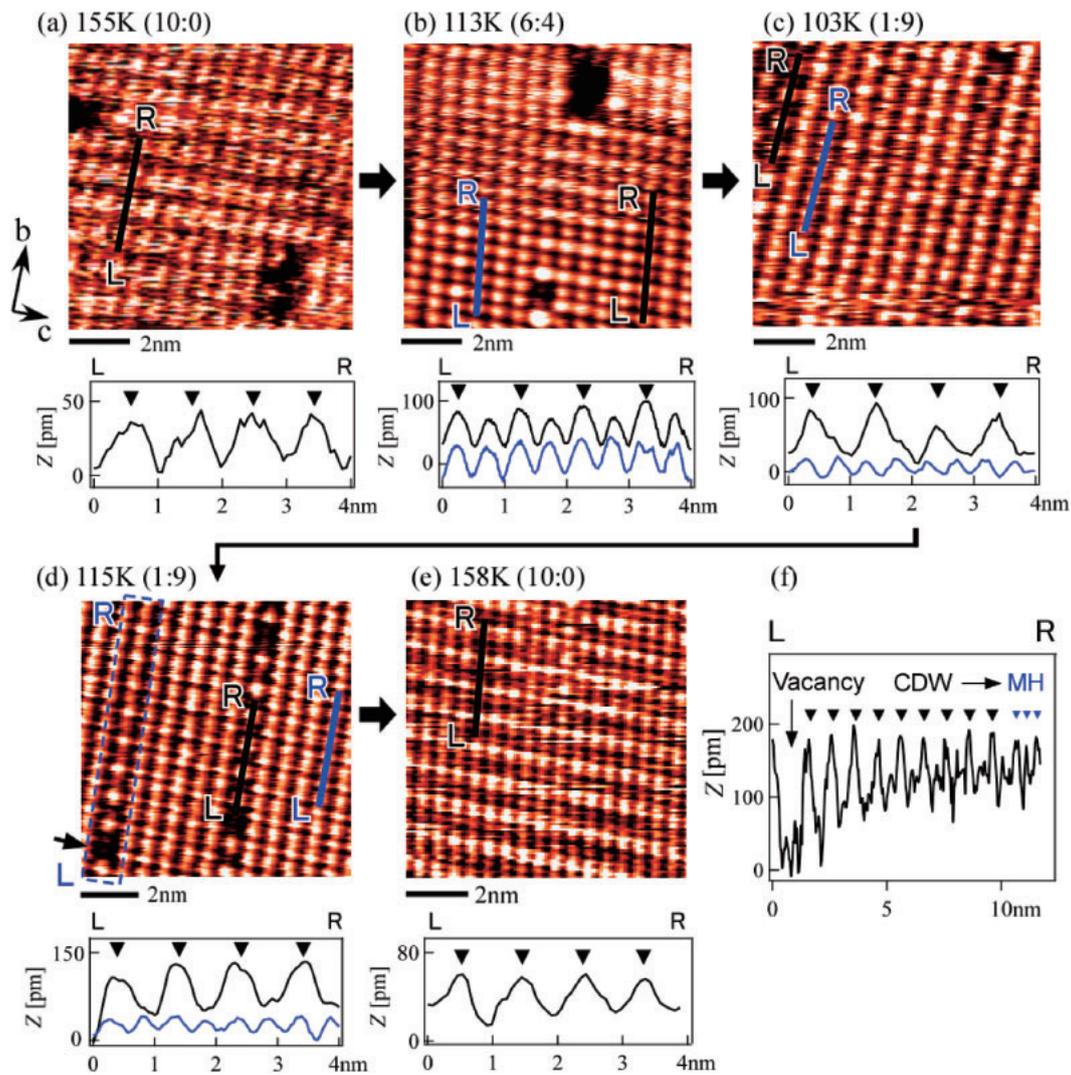


Fig. 4. (Color) Variation in the STM images of the $[\text{Pd}(\text{cptn})_2\text{Br}]\text{Br}_2$ surface with decreasing (a–c) and increasing (d, e) sample temperature, showing the temperature dependence of the phase transition between the CDW and MH phases. The measurement conditions (V_s, I_t) were (a) (2.0 V, 0.2 nA), (b) (3.5 V, 0.1 nA), (c) (4.0 V, 0.08 nA), (d) (3.3 V, 0.08 nA), and (e) (3.8 V, 0.08 nA). The area ratios between the CDW and MH phases shown above the STM images were obtained from the average of the STM images measured over $25 \times 25 \text{ nm}^2$ areas at different locations at each temperature. (f) Cross section along the 1D chain surrounded by the dashed rectangle in (d).

left of Fig. 4(d), where only one defect exists in the chain, showing a gradual change in the structure from the CDW phase near the defect located near letter L (bottom left) to the MH phase along the chain (L–R). These results suggest that the CDW phase tends to be pinned by defects at low temperatures and grows with increasing temperature. As shown in Figs. 4(c) and 4(d), the effect of defects on the neighboring chains looks weak, which, however, may affect the critical temperature. This effect may be due to the strain around the defects, although it has not yet been confirmed.

Another noteworthy point is that the CDW/MH area ratio at around 115 K was different between the surfaces observed upon the temperature being decreased [(b) 113 K, 6 : 4] and increased [(e) 115 K, 1 : 9], i.e., although the latter temperature is slightly higher, the ratio of the CDW phase is lower. The MH state remains even at a higher temperature when the temperature is increased. The hysteresis, which is a characteristic of the first-order phase transition and was observed in a previous work by macroscopic methods such as Raman spectroscopy,¹¹⁾ was directly observed at the atomic scale for the first time.

As reported in a previous paper, the Pd–Pd distance in the *b*-axis direction becomes closer for a sample with a longer alkyl chain, which increases critical temperature by ~ 30 K when one C atom in the alkyl chain is added.¹³⁾ As expected, the critical temperature of ~ 100 K observed in this experiment for the sample without alkyl chains is lower than that observed for $[\text{Pd}(\text{en})_2\text{Br}](\text{C}_5\text{-Y})_2 \cdot \text{H}_2\text{O}$ of 205 K,¹³⁾ which is of a similar order despite their structures being different from each other. Theoretical calculations are necessary to obtain better understanding of these results. The analysis of the growth of the CDW phase in the intermediate state is important to clarify details of the phase transition, such as the interactions in 1D chains and between 1D chains. The analysis of the fluctuations of the two phases and the effect of alkyl chains will also be an interesting topic for future study. These analyses are under consideration.

4. Conclusions

We succeeded in the direct observation by STM of the phase transition between the CDW and MH phases in $[\text{Pd}(\text{cptn})_2\text{Br}]\text{Br}_2$, in which a short ligand without alkyl

chains was used to form a rigid crystal lattice to reduce the effect of structural changes with temperature. The hysteresis in the temperature dependence of the ratio between the CDW and MH phase areas, which is characteristic of the first-order phase transition, was directly observed at the atomic scale. The pinning of the CDW phase by defects was observed below the critical temperature, suggesting the growth of the CDW phase with defects as nuclei.

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